

Metasurface Integrated in Thin Solar Cells for Index Modulation

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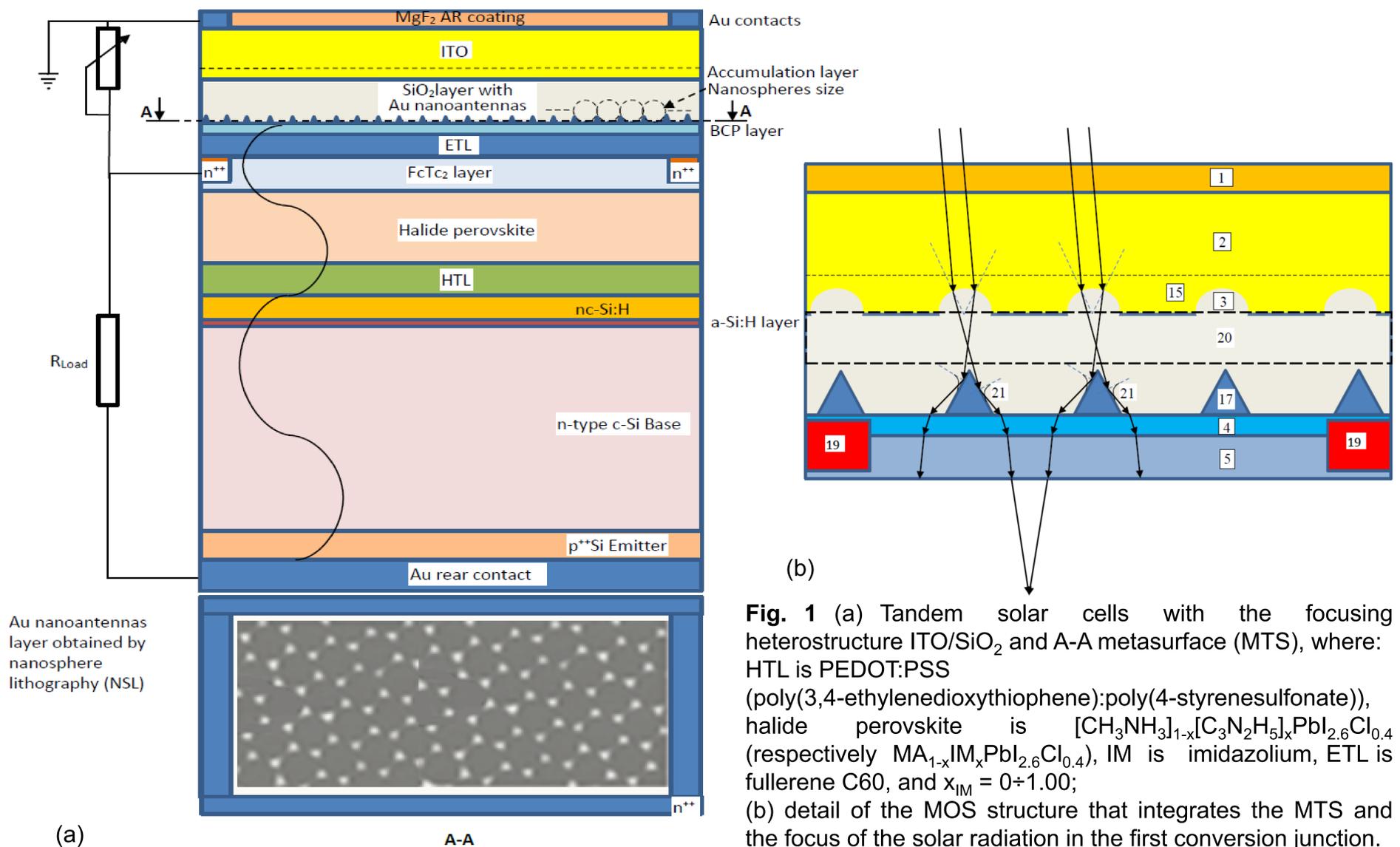
1. INTRODUCTION

In order to exceed this limit of the single-junction device and also capable of reducing losses, *i.e.* thermalization loss and proper utilization of solar spectrum, is essential to form efficient tandem solar cells: perovskite solar cell (PSCs) on silicon single junction. Size-tunable Ag nanoantennas for integrated metasurfaces (MTS) achieved by nanosphere lithography enable that the refractive index for accumulation layer (ITO) of solar cell to be dynamic controlled by voltage on ITO/SiO₂ junction for focusing and trapping sunlight in the active area of the tandem cell. The OptiFDTD and GenPro4 softwares allow us to design, analyze and test this modern photonic device with arbitrary model geometries and places no restriction on the material properties of the tandem cells for wave propagation, scattering, reflection, diffraction, polarization and nonlinear phenomena.

2. METHODOLOGY

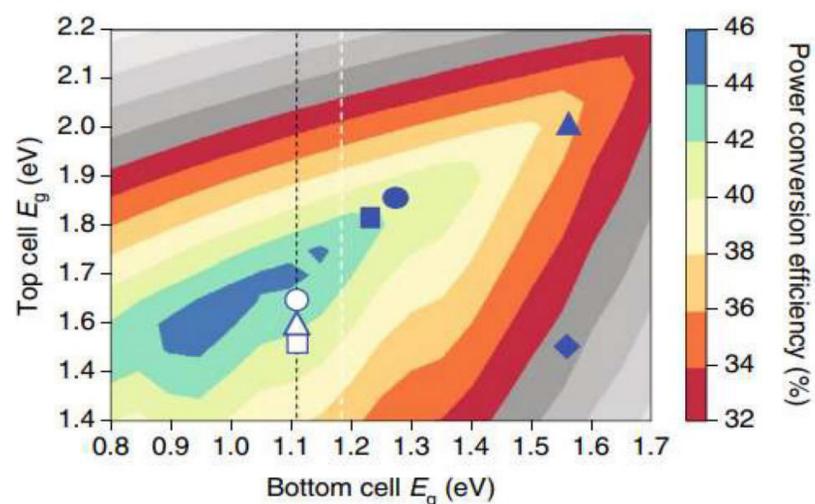
The absorption of upper layers can be dramatically enhanced using a halide perovskite in order to obtain an absorber/Si solar cell architecture for environmentally friendly photovoltaic conversion technology. Adding an extra layer of ferrocenyl-bis-thiophene-2-carboxylate (FcTc₂) further enhancing the performance and stability of inverted perovskite solar cells is possible².

The upper layers can be optimized for index modulation to focus the sunlight in the active region based on carrier density, electron band diagram, permittivity of accumulation layer³. The modeled structure of the tandem solar cell is presented in Fig. 1(a), 1(b).



3. RESULTS

The black dotted line in Fig. 2 represents the ~1.1eV bandgap of c-Si. Optical simulation indicated that the most efficient bandgap alignment of the subcells is 1.7eV for the top cell and 1.1eV for the bottom cell in a solar tandem. Combination of perovskite and silicon solar cells in tandem configuration is of great interest due to the possibility of boosting conversion efficiencies above 40%. The maximum conversion efficiency can be further expanded by a suitable light trapping in the first active region by controlling the refractive index of the n-ITO semiconductor deposited on a SiO₂ layer profiled on a metasurface.



REFERENCES

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